





ZXTP2041F

40V PNP MEDIUM POWER TRANSISTOR IN SOT23

Features

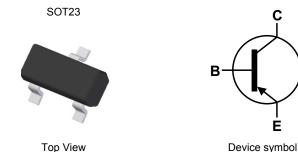
- BV_{CEO} > -40V
- I_C = -1A High Continuous Current
- I_{CM} = -2A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -500mV @ -1A
- R_{SAT} = 350mΩ for a Low Equivalent On-resistance
- Complementary NPN type: ZXTN2040F
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

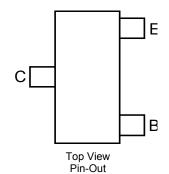
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202. Method 208 ©3
- Weight: 0.008 grams (approximate)

Application

- Power MOSFET gate driving
- Low loss power switching





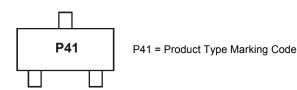
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP2041FTA	P41	7	8	3,000

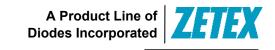
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information







ZXTP2041F

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	I _{CM}	-2	Α
Base Current	I _B	-200	mA
Peak Base Current	Івм	-1	А

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	С	310	mW	
Power Dissipation	(Note 6)	P _D	350		
Thermal Desistance, Junction to Ambient	(Note 5)		403	00/1/1	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	357	°C/W	
Thermal Resistance, Junction to Leads (Note 7)		$R_{ heta JL}$	350	°C/W	
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C		

ESD Ratings (Note 8)

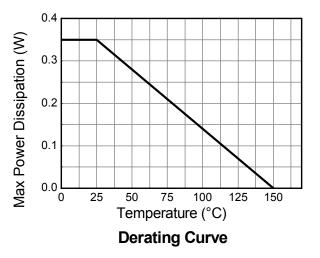
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

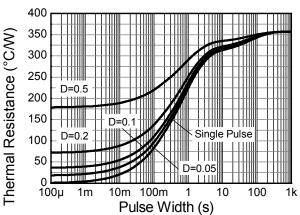
Notes:

- 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the device is mounted on 15 mm x 15mm 1oz copper.
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

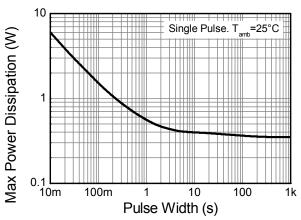


Thermal Characteristics and Derating Information





Transient Thermal Impedance



Pulse Power Dissipation





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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

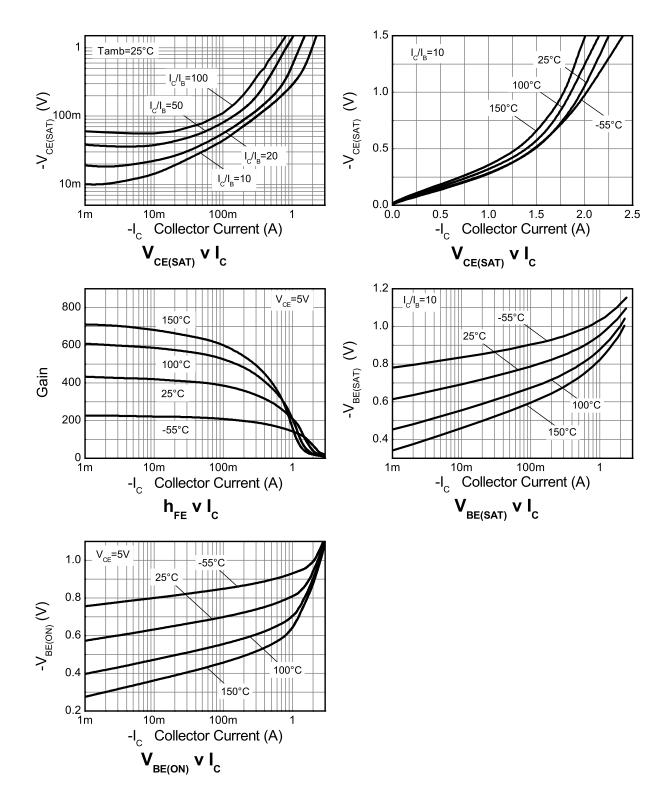
C	haracteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV_CBO	-40	-	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)		BV_CEO	-40	-	-	V	I _C = -10mA
Emitter-Base Brea	akdown Voltage	BV_{EBO}	-7	-	-	V	$I_E = -100 \mu A$
Collector Cutoff C	urrent	I _{CBO}	-	-	-100	nA	V _{CB} = -30V
Emitter Cutoff Cu	rrent	I _{EBO}	-	-	-100	nA	V _{EB} = -5.6V
Emitter Cutoff Cu	rrent	I _{CES}	-	-	-100	nA	V _{CE} = -30V
			300	-	-		$I_{C} = -1 \text{mA}, V_{CE} = -5 \text{V}$
			300	-	800		I _C = -100mA, V _{CE} = -5V
DC current transfe	er Static ratio (Note 9)	h _{FE}	250	-	-		$I_C = -500 \text{mA}, V_{CE} = -5 \text{V}$
			160	-	-		I _C = -1A, V _{CE} = -5V
			30	-	-		I _C = -2A, V _{CE} = -5V
			-	-	-200		I _C = -100mA, I _B = -1mA
Collector-Emitter	Saturation Voltage (Note 9)	V _{CE(sat)}	-	-	-350	mV	I _C = -500mA, I _B = -20mA
			-	-	-500		$I_C = -1A$, $I_B = -100mA$
Base-Emitter Saturation Voltage (Note 9)		$V_{BE(sat)}$	-	-	-1.1	V	I _C = -1A, I _B = -100mA
Base-Emitter Turn-on Voltage (Note 9)		V _{BE(on)}	-	-	-1.0	V	I _C = -1A, V _{CE} = -5V
Transitional Frequency		f _T	150	300	-	MHz	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V},$ f = 100MHz
Output capacitance		C _{obo}	-	-	10	pF	V _{CB} = -10V, f = 1MHz,
	Delay Time		-	34.9	-		
Switching Time	Rise Time	t _(r)	-	19.2	-		$V_{CC} = -10V$, $I_{C} = -500$ mA,
Switching Time	Storage Time	t _(s)	-	249	-	ns	$I_{B1} = -I_{B2} = -25 \text{mA}$
	Fall Time	t _(f)	-	62	-	1	

Notes: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.





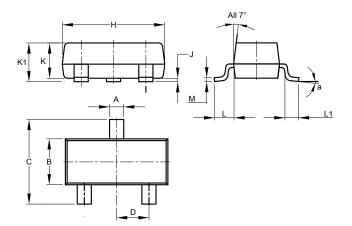
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Package Outline Dimensions

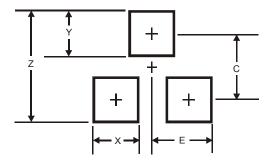
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	8°				
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
X	0.8		
Υ	0.9		
С	2.0		
ш	1.35		





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